

L Number	Hits	Search Text	DB	Time stamp
-	442	laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/20 15:21
-	95	laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode and (monolithic mono adj lithic)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/20 14:13
-	81	laser near semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode and (monolithic mono adj lithic)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/20 15:18
-	14	(laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode and (monolithic mono adj lithic)) not (laser near semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode and (monolithic mono adj lithic))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/20 15:18
-	347	(laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode) not (laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode and (monolithic mono adj lithic))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/20 15:21
-	59	((laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode) not (laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode and (monolithic mono adj lithic))) and ((multimode (multi adj mode)) MMI)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/20 15:38
-	0	20020064201.URPN.	USPAT	2002/08/20 15:23
-	2	"11068242"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/20 15:38
-	4	898346.URPN.	USPAT	2002/08/20 15:56
-	1	1999-134918.NRAN.	DERWENT	2002/08/20 15:56
-	1	3244116.URPN.	USPAT	2002/08/20 15:58
-	4	898346.URPN.	USPAT	2002/08/20 15:58
-	1224	372/\$.ccls. and ((multimode (multi adj mode)) MMI)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:12
-	589	(372/\$.ccls. and ((multimode (multi adj mode)) MMI)) and (waveguide (wave adj guide))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:08
-	394	((372/\$.ccls. and ((multimode (multi adj mode)) MMI)) and (waveguide (wave adj guide))) and semiconductor adj laser	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:09

		578 ((372/\$.ccls. and ((multimode (multi adj mode)) MMI)) and (waveguide (wave adj guide))) and laser	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:09
		186 (((372/\$.ccls. and ((multimode (multi adj mode)) MMI)) and (waveguide (wave adj guide))) and semiconductor adj laser) and active adj layer	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:10
		196 (((372/\$.ccls. and ((multimode (multi adj mode)) MMI)) and (waveguide (wave adj guide))) and semiconductor adj laser) and active adj2 layer	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:10
		35 (((372/\$.ccls. and ((multimode (multi adj mode)) MMI)) and (waveguide (wave adj guide))) and semiconductor adj laser) and active adj layer) and laser adj emission	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:10
		22 372/\$.ccls. and (((multimode (multi adj mode)) adj interference) MMI)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:22
		0 20010014109.URPN.	USPAT	2002/08/21 07:16
		4 ("4827482" "5475776" "5799119" "5949931").PN.	USPAT	2002/08/21 07:17
		1 6205163.URPN.	USPAT	2002/08/21 07:18
		1612 (372/50).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:23
		892 ((372/50).CCLS.) and (waveguide wave adj guide)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 07:31
		484 (385/28).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:01
		0 ("l1 and semiconductor adj laser").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:02
		56 ((385/28).CCLS.) and semiconductor adj laser	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:07
		253 ((385/28).CCLS.) and laser	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:07
		197 (((385/28).CCLS.) and laser) not (((385/28).CCLS.) and semiconductor adj laser)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:08
		556 (385/17).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:08
		49 ((385/17).CCLS.) and semiconductor adj laser	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:09
		48 (((385/17).CCLS.) and semiconductor adj laser) not (((385/28).CCLS.) and semiconductor adj laser)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2002/08/21 15:09